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#### bq32000

SLUS900E - DECEMBER 2008 - REVISED AUGUST 2015

# bq32000 Real-Time Clock (RTC)

Technical

Documents

## 1 Features

- Automatic Switchover to Backup Supply
- I<sup>2</sup>C Interface Supports Serial Clock up to 400 kHz
- Uses 32.768-kHz Crystal With –63-ppm to +126-ppm Adjustment
- Integrated Oscillator-Fail Detection
- 8-Pin SOIC Package
- -40°C to 85°C Ambient Operating Temperature

## 2 Applications

• General Consumer Electronics

## 3 Description

Tools &

Software

The bq32000 device is a compatible replacement for industry standard real-time clocks.

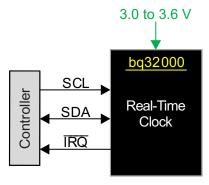
The bq32000 features an automatic backup supply with integrated trickle charger. The backup supply can be implemented using a capacitor or nonrechargeable has battery. The bq32000 а programmable calibration adjustment from -63 ppm to +126 ppm. The bq32000 registers include an OF (oscillator fail) flag indicating the status of the RTC oscillator, as well as a STOP bit that allows the host processor to disable the oscillator. The time registers are normally updated once per second, and all the registers are updated at the same time to prevent a timekeeping glitch. The bq32000 includes automatic leap-year compensation.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
bq32000	SOIC (8)	4.90 mm x 3.91 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

#### **Simplified Schematic**



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from	Revision	D (N	ovember	2011)	to	<b>Revision E</b>
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•	Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and	
	Mechanical, Packaging, and Orderable Information section.	1
•	Added Storage Temperature to Absolute Maximum Ratings	4
•	Changed $V_{CC} = 0$ to VCC needs a pulse	5



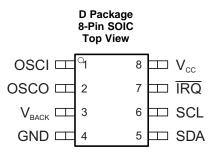
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## 5 Pin Configuration and Functions



#### **Pin Functions**

PIN		1/0	DECODIDETION			
NAME	NO.	I/O	DESCRIPTION			
POWER AND GR	ROUND					
GND	4	-	Ground			
V <sub>BACK</sub>	3	-	Backup device power			
V <sub>CC</sub>	8	-	ain device power			
SERIAL INTERF	ACE					
SCL	6	Ι	I <sup>2</sup> C serial interface clock			
SDA	5	I/O	l <sup>2</sup> C serial data			
INTERRUPT						
ĪRQ	7	0	Configurable interrupt output. Open-drain output.			
OSCILLATOR						
OSCI	1	-	Oscillator input			
OSCO	2	-	Oscillator output			

#### Specifications 6

## 6.1 Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
	V <sub>CC</sub> to GND	-0.3	4	V
Input voltage, V <sub>IN</sub>	All other pins to GND	-0.3	$V_{CC} + 0.3$	V
Dperating junction temperature, T <sub>J</sub>		-40	150	°C
Storage temperature, T <sub>stg</sub>		-60	150	°C

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## 6.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>	2000	
V <sub>(ESD)</sub>	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all $\ensuremath{pins^{(2)}}$	500	V

JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. (1)

(2)

### 6.3 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V <sub>CC</sub>	Supply voltage, V <sub>CC</sub> to GND	3		3.6	V
T <sub>A</sub>	Operating free-air temperature	-40		85	°C
fo	Crystal resonant frequency		32.768		kHz
R <sub>S</sub>	Crystal series resistance			70	kΩ
CL	Crystal load capacitance	10.8	12	13.2	pF

## 6.4 Thermal Information

over operating free-air temperature range (unless otherwise noted)

	C(top)   Junction-to-case (top) thermal resistance     Junction-to-board thermal resistance     Junction-to-top characterization parameter	bq32000	
		D (SOIC)	UNIT
		8 PINS	
$R_{ extsf{ heta}JA}$	Junction-to-ambient thermal resistance	114.8	°C/W
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	59.1	°C/W
$R_{ heta JB}$	Junction-to-board thermal resistance	55.5	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	11.9	°C/W
ΨJT	Junction-to-board characterization parameter	55	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application (1) report, SPRA953.

#### 6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWE	R SUPPLY					
I <sub>CC</sub>	V <sub>CC</sub> supply current			100		μA
V		Operating	1.4		V <sub>CC</sub>	V
V <sub>BACK</sub>	Backup supply voltage	Switchover	2.0		V <sub>CC</sub>	V
IBACK	Backup supply current	$V_{CC}$ needs a pulse <sup>(1)</sup> , $V_{BACK}$ = 3 V, Oscillator on, $T_A$ = 25°C		1.2	1.5	μA
LOGIC	LEVEL INPUTS					
V <sub>IL</sub>	Input low voltage				0.3 V <sub>CC</sub>	V
V <sub>IH</sub>	Input high voltage		0.7 V <sub>CC</sub>			V
I <sub>IN</sub>	Input current	$0 V \le V_{IN} \le V_{CC}$	-1		1	μA
LOGIC	LEVEL OUTPUTS					
V <sub>OL</sub>	Output low voltage	$I_{OL} = 3 \text{ mA}$			0.4	V
۱ <sub>L</sub>	Leakage current		-1		1	μA
REAL-	TIME CLOCK CHARACTER	ISTICS				
	Pre-calibration accuracy	$V_{CC}$ = 3.3 V, $V_{BACK}$ = 3 V, Oscillator on, $T_A$ = 25°C		±35 <sup>(2)</sup>		ppm

The currents measured after issuing a pulse on V<sub>CC</sub>. The pulse amplitude 0-V<sub>CC</sub>; pulse width min 1 ms.
Typical accuracy is measured using reference board design and KDS DMX-26S surface-mount 32.768-kHz crystal. Variation in board design and crystal section results in different typical accuracy.

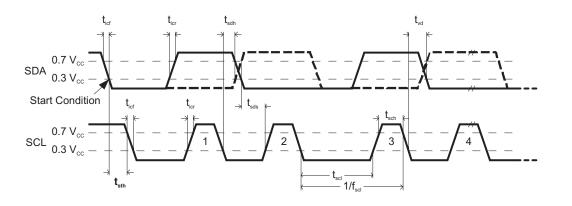
## 6.6 I<sup>2</sup>C Timing Requirements

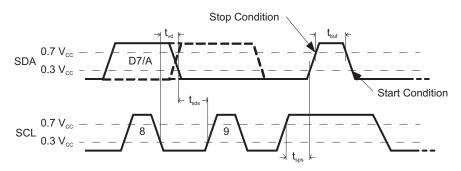
		STANDAR	D MODE	FAST MOD	E	UNIT
		MIN	MAX	MIN	MAX	UNIT
f <sub>scl</sub>	I <sup>2</sup> C clock frequency	0	100	0	400	kHz
t <sub>sch</sub>	I <sup>2</sup> C clock high time	4		0.6		μs
t <sub>scl</sub>	I <sup>2</sup> C clock low time	4.7		1.3		μs
t <sub>sp</sub>	I <sup>2</sup> C spike time	0	50	0	50	ns
t <sub>sds</sub>	I <sup>2</sup> C serial data setup time	250		100		ns
t <sub>sdh</sub>	I <sup>2</sup> C serial data hold time	0		0		ns
t <sub>icr</sub>	I <sup>2</sup> C input rise time		1000	20 + 0.1C <sub>b</sub> <sup>(1)</sup>	300	ns
t <sub>icf</sub>	I <sup>2</sup> C input fall time		300	20 + 0.1C <sub>b</sub> <sup>(1)</sup>	300	ns
t <sub>ocf</sub>	I <sup>2</sup> C output fall time		300	20 + 0.1C <sub>b</sub> <sup>(1)</sup>	300	μs
t <sub>buf</sub>	I <sup>2</sup> C bus free time	4.7		1.3		μs
t <sub>sts</sub>	I <sup>2</sup> C Start setup time	4.7		0.6		μs
t <sub>sth</sub>	I <sup>2</sup> C Start hold time	4		0.6		μs
t <sub>sps</sub>	I <sup>2</sup> C Stop setup time	4		0.6		μs
t <sub>vd(data)</sub>	Valid data time (SCL low to SDA valid)		1		1	μs
t <sub>vd(ack)</sub>	Valid data time of ACK (ACK signal from SCL low to SDA low)		1		1	μs

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(1)  $C_b$  = total capacitance of one bus line in pF

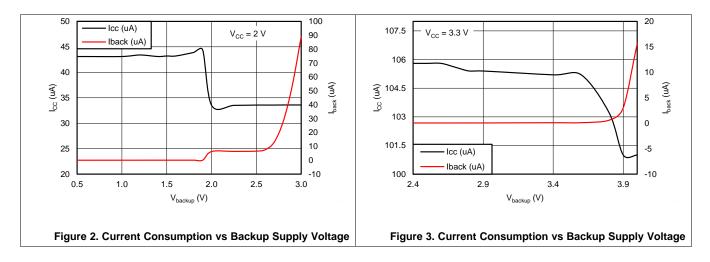








## 6.7 Typical Characteristics



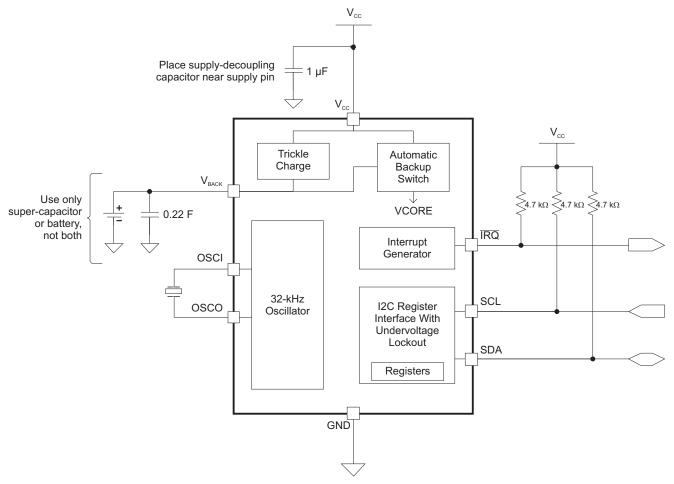


## 7 Detailed Description

### 7.1 Overview

The bq32000 is a real-time clock that features an automatic backup supply with an integrated trickle charger.

## 7.2 Functional Block Diagram



NOTE: All pullup resistors should be connected to V<sub>CC</sub> such that no pullup is applied during backup supply operation.

#### 7.3 Feature Description

### 7.3.1 IRQ Function

<u>The</u> IRQ pin of the bq32000 functions as a general-purpose output or a frequency test output. The function of IRQ is configurable in the device register space by setting the FT, FTF, and OUT bits. On initial power cycles, the OUT bit is set to one, and the FTF and FT bits are set to zero. On subsequent power-ups, with backup supply present, the OUT bit remains unchanged, and the FTF and FT bits are set to zero. When operating on backup supply, the IRQ pin function is unused. IRQ pullup resistor should be tied to V<sub>CC</sub> to prevent IRQ operation when operating on backup supply. The effect of the calibration logic is not normally observable when IRQ is configured to output 1 Hz. The calibration logic functions by periodically adjusting the width of the 1-Hz clock. The calibration effect is observable only every eight or sixteen minutes, depending on the sign of the calibration.



## Feature Description (continued)

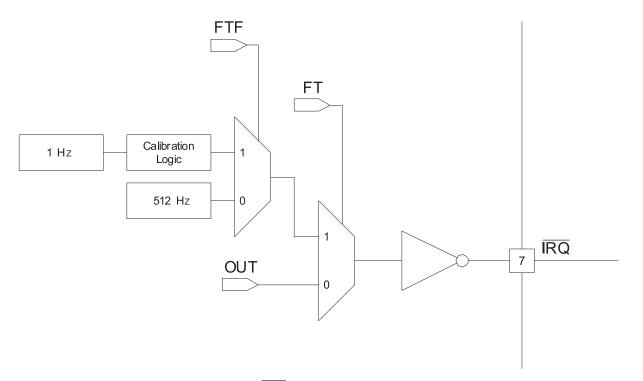


Figure 4.	<b>IRQ</b> Pin	Functional	Diagram
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	Table	1.	IRQ	Function
--	-------	----	-----	----------

FT	OUT	FTF	<b>IRQ</b> STATE
1	Х	1	1 Hz
1	Х	0	512 Hz
0	1	Х	1
0	0	Х	0

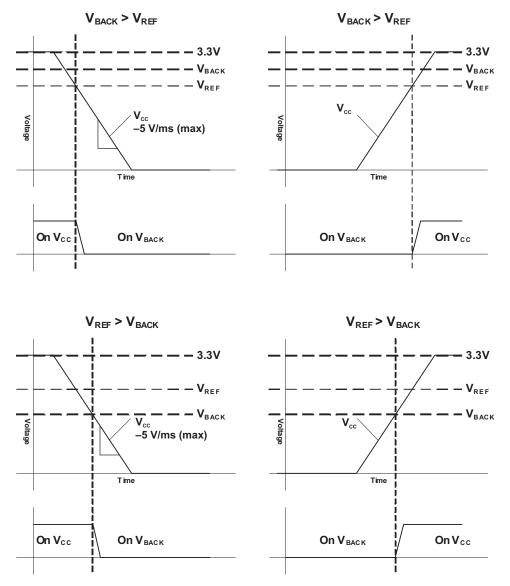


#### 7.3.2 VBACK Switchover

The bq32000 has an internal switchover circuit that causes the device to switch from main power supply to backup power supply when the voltage of the main supply pin V<sub>CC</sub> drops below a minimum threshold. The V<sub>BACK</sub> switchover circuit uses an internal reference voltage V<sub>REF</sub> derived from the on-chip bandgap reference; V<sub>REF</sub> is approximately 2.8 V. The device switches to the V<sub>BACK</sub> supply when V<sub>CC</sub> is less than the lesser of V<sub>BACK</sub> or V<sub>REF</sub>. Similarly, the device switches to the V<sub>CC</sub> supply when V<sub>CC</sub> is greater than either V<sub>BACK</sub> or V<sub>REF</sub>.

Some registers are reset to default values when the RTC switches from main power supply to backup power supply. Please see the register definitions to determine what register bits are effected by a backup switchover (effected bits have their reset value (1/0) shown for 'Cycle', bits that are unchanged by backup are marked 'UC').

The time keeping registers can take up to 1 second to update after the RTC switches from backup power supply to main power supply.





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#### 7.3.3 Trickle Charge

The bq32000 includes a trickle charge circuit to maintain the charge of the backup supply when a super capacitor is used. The trickle charge circuit is implemented as a series of three switches that are independently controlled by setting the TCHE[3:0], TCH2, and TCFE bits in the register space.

TCHE[3:0] must be written as 0x5h and TCH2 as 1 to close the trickle charge switches and enable charging of the backup supply from  $V_{CC}$ . Additionally, TCFE can be set to 1 to bypass the internal diode and boost the charge voltage of the backup supply. All trickle charge switches are opened when the device is initially powered on and each time the device switches from the main supply to the backup supply. The trickle charge circuit is intended for use with super capacitors; however, it can be used with a rechargeable battery under certain conditions. Care must be taken not to overcharge a rechargeable battery when enabling trickle charge. Follow all charging guidelines specific to the rechargeable battery or super capacitor when enabling trickle charge.

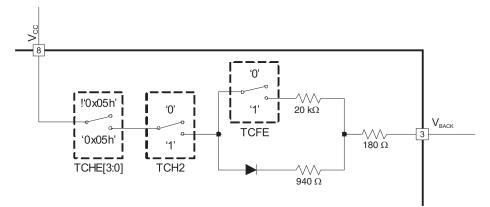


Figure 6. Trickle Charge Switch Functional Diagram

#### 7.4 Device Functional Modes

When the device switches from the main power supply to backup supply, the Time keeping register Registers [0-9] cannot be accessed via the I2C. The access to these registers are only when  $V_{CC} > V_{ref}$ .

The Time keeping registers can take up to 1 second to update after the device switches from backup power supply to main power supply.

#### 7.5 Programming

#### 7.5.1 I<sup>2</sup>C Serial Interface

The I<sup>2</sup>C interface allows control and monitoring of the RTC by a microcontroller. I<sup>2</sup>C is a two-wire serial interface developed by Philips Semiconductor (see I<sup>2</sup>C-Bus Specification, Version 2.1, January 2000).

The bus consists of a data line (SDA) and a clock line (SCL) with off-chip pullup resistors. When the bus is idle, both SDA and SCL lines are pulled high.

A master device, usually a microcontroller or a digital signal processor, controls the bus. The master is responsible for generating the SCL signal and device addresses. The master also generates specific conditions that indicate the START and STOP of data transfer.

A slave device receives and/or transmits data on the bus under control of the master device. This device operates only as a slave device.

 $I^2C$  communication is initiated by a master sending a start condition, a high-to-low transition on the SDA I/O while SCL is held high. After the start condition, the device address byte is sent, most-significant bit (MSB) first, including the data direction bit (R/W). After receiving a valid address byte, this device responds with an acknowledge, a low on the SDA I/O during the high of the acknowledge-related clock pulse. This device responds to the  $I^2C$  slave address 11010000b for write commands and slave address 11010001b for read commands.

This device does not respond to the general call address.



#### **Programming (continued)**

A data byte follows the address acknowledge. If the R/W bit is low, the data is written from the master. If the R/W bit is high, the data from this device are the values read from the register previously selected by a write to the subaddress register. The data byte is followed by an acknowledge sent from this device. Data is output only if complete bytes are received and acknowledged.

A stop condition, which is a low-to-high transition on the SDA I/O while the SCL input is high, is sent by the master to terminate the transfer. A master device must wait at least 60 µs after the RTC exits backup mode to generate a START condition.

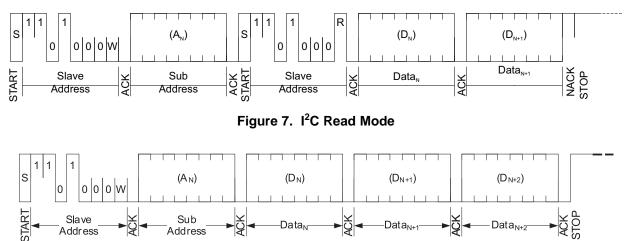


Figure 8. I<sup>2</sup>C Write Mode

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### 7.6 Register Maps

ADDRESS (HEX)	REGISTER NAME	DESCRIPTION							
0x00	SECONDS	Clock seconds and STOP bit							
0x01	MINUTES	Clock minutes							
0x02	CENT_HOURS	Clock hours, century, and CENT_EN bit							
0x03	DAY	Clock day							
0x04	DATE	Clock date							
0x05	MONTH	Clock month							
0x06	YEARS	Clock years							
0x07	CAL_CFG1	Calibration and configuration							
0x08	TCH2	Trickle charge enable							
0x09	CFG2	Configuration 2							
	(HEX) 0x00 0x01 0x02 0x03 0x04 0x05 0x06 0x07 0x08	ADDRESS (HEX)REGISTER NAME0x00SECONDS0x01MINUTES0x02CENT_HOURS0x03DAY0x04DATE0x05MONTH0x06YEARS0x07CAL_CFG10x08TCH2							

#### Table 2. Normal Registers

#### **Table 3. Special Function Registers**

REGISTER	ADDRESS (HEX)	REGISTER NAME	DESCRIPTION		
32	0x20	SF KEY 1	Special function key 1		
33	0x21	SF KEY 2	Special function key 2		
34	0x22	SFR	Special function register		

#### 7.6.1 I<sup>2</sup>C Read After Backup Mode

The time keeping registers can take up to 1 second to update after the RTC switches from backup power supply to main power supply. An I<sup>2</sup>C read of the RTC that starts before the update has completed will return the time when the RTC enters backup mode. To ensure that the correct time is read after backup mode, the host should wait longer than 1 second after the main supply is greater than 2.8 V and  $V_{BACK}$ .

#### 7.6.2 Normal Register Descriptions

#### 7.6.2.1 SECONDS Register (address = 0x00) [reset = 0XXXXXXb]

Description - Clock seconds and STOP bit

7	6	5	4	3	2	1	0	BIT(S)		
STOP		10_SECOND			1_SECOND					
r/w		r/w			r/w					
0	Х	Х	Х	Х	Х	Х	Х	Initial		
UC	UC	UC	UC	UC	UC	UC	UC	Cycle		
STOP	power, on a and then wr 0 Nor	Oscillator stop. The STOP bit is used to force the oscillator to stop oscillating. STOP is set to 0 on initial application of power, on all subsequent power cycles STOP remains unchanged. On initial power application STOP can be written to 1 and then written to 0 to force start the oscillator. Normal 1 Stop								
10_SECOND	clock. Valid 10_SECON	BCD of tens of seconds. The 10_SECOND bits are the BCD representation of the number of tens of seconds on the clock. Valid values are 0 to 5. If invalid data is written to 10_SECOND, the clock will update with invalid data in 10_SECOND until the counter rolls over; thereafter, the data in 10_SECOND is valid. Time keeping registers can take up to 1 second to update after the RTC switches from backup power supply to main power supply.								
1_SECOND	are 0 to 9. I rolls over; th	f invalid data is nereafter, the da	written to 1_SE ata in 1_SECON	COND, the cloc	k will update wit keeping registe	number of seco th invalid data in ers can take up	1_SECOND u			

#### Figure 9. SECONDS Register



#### 7.6.2.2 MINUTES Register (address = 0x01) [reset = 1XXXXXXb]

Description – Clock minutes

7	6	5	4	3	2	1	0	BIT(S)		
OF		10_MINUTE			1_MI	NUTE		Name		
r/w		r/w		r/w				Read/Write		
1	Х	Х	Х	Х	Х	Х	Х	Initial		
0	UC	UC	UC	UC	UC	UC	UC	Cycle		
OF	consecutive When OF is four consec 0 No 1 Fai	1 Failure detected								
10_MINUTE	Valid values the counter	BCD of tens of minutes. The 10_MINUTE bits are the BCD representation of the number of tens of minutes on the clock. Valid values are 0 to 5. If invalid data is written to 10_MINUTE, the clock will update with invalid data in 10_MINUTE until the counter rolls over; thereafter, the data in 10_MINUTE is valid. Time keeping registers can take up to 1 second to update after the RTC switches from backup power supply to main power supply.								
1_MINUTE	0 to 9. If inv over; therea	update after the RTC switches from backup power supply to main power supply. BCD of minutes. The 1_MINUTE bits are the BCD representation of the number of minutes on the clock. Valid values are 0 to 9. If invalid data is written to 1_MINUTE, the clock will update with invalid data in 1_MINUTE until the counter rolls over; thereafter, the data in 1_MINUTE is valid. Time keeping registers can take up to 1 second to update after the RTC switches from backup power supply to main power supply.								

## Figure 10. MINUTES Register

#### 7.6.2.3 CENT\_HOURS Register (address = 0x02) [reset = XXXXXXXb]

Description - Clock hours, century, and CENT\_EN bit

7	6	5	4	3	2	1	0	BIT(S)		
CENT_EN	CENT	10_H	IOUR		1_HOUR					
r/w	r/w	r/	w		r/	w		Read/Write		
Х	Х	Х	Х	Х	Х	Х	Х	Initial		
UC	UC	UC	UC	UC	UC	UC	UC	Cycle		
CENT_EN	tracks the c 0 Cer									
CENT	Century. Th the year cou	Century enabled Century. The CENT bit tracks the century when century timekeeping is enabled. The clock toggles the CENT bit when the year count rolls from 99 to 00. Because the clock compliments the CENT bit, the user can define the meaning of CENT (1 for current century and 0 for next century, or 0 for current century and 1 for next century).								
10_HOUR	BCD of tens of hours (24-hour format). The 10_HOUR bits are the BCD representation of the number of tens of hours on the clock, in 24-hour format. Valid values are 0 to 2. If invalid data is written to 10_HOUR, the clock will update with invalid data in 10_HOUR until the counter rolls over; thereafter, the data in 10_HOUR is valid. Time keeping registers can take up to 1 second to update after the RTC switches from backup power supply to main power supply.									
1_HOUR	hour format 1_HOUR ur	BCD of hours (24-hour format). The 1_HOUR bits are the BCD representation of the number of hours on the clock, in 24- hour format. Valid values are 0 to 9. If invalid data is written to 1_HOUR, the clock will update with invalid data in 1_HOUR until the counter rolls over; thereafter, the data in 1_HOUR is valid. Time keeping registers can take up to 1 second to update after the RTC switches from backup power supply to main power supply.								

#### Figure 11. CENT\_HOURS Register

## 7.6.2.4 DAY Register (address = 0x03) [reset = 00000XXXb]

Description – Clock day

			5												
7	6	5	4	3	2	1	0	BIT(S)							
		RSVD				Name									
r/w						r/w		Read/Write							
0	0	0	0	0	Х	Х	Х	Initial							
0	0	0	0	0	UC	UC	UC	Cycle							
RSVD	Reserved. T	he RSVD bits s	hould always b	e written as 0.											
DAY	and represe in DAY is va	nt the days fron	n Sunday to Sa ng registers can	are the BCD rep turday. DAY upo take up to 1 se	dates if set to 0	until the counter	r rolls over; the	reafter, the data							

#### Figure 12. DAY Register

- 1 Sunday
- 2 Monday
- 3 Tuesday
- 4
- Wednesday
- 5 Thursday
- 6 Friday 7
  - Saturday

#### 7.6.2.5 DATE Register (address = 0x04) [reset = 00XXXXXXb]

#### Description - Clock date

7	6	5	4	3	2	1	0	BIT(S)	
R	SVD	10_[	DATE		1_DATE				
I	r/w	r/	′w		r/w			Read/Write	
0	0	Х	Х	Х	Х	Х	Х	Initial	
0	0	UC	UC	UC	UC	UC	UC	Cycle	
RSVD	Reserved. T	he RSVD bits s	should always b	e written as 0.					
I0_DATE	BCD of tens	of date. The 1	0_DATE bits are	e the BCD repre	sentation of the	tens of date on	the clock. Val	id values are 0 to	

#### Figure 13. DATE Register

3<sup>(1)</sup>. If invalid data is written to 10\_DATE, the clock will update with invalid data in 10\_DATE until the counter rolls over; thereafter, the data in 10\_DATE is valid. Time keeping registers can take up to 1 second to update after the RTC switches from backup power supply to main power supply.

1\_DATE BCD of date. The 1\_DATE bits are the BCD representation of the date on the clock. Valid values are 0 to 9<sup>(1)</sup>. If invalid data is written to 1\_DATE, the clock will update with invalid data in 1\_DATE until the counter rolls over; thereafter, the data in 1\_DATE is valid. Time keeping registers can take up to 1 second to update after the RTC switches from backup power supply to main power supply.

(1) 10\_DATE and 1\_DATE must form a valid date, 01 to 31, dependent on month and year.



#### 7.6.2.6 MONTH Register (address = 0x05) [reset = 000XXXXXb]

Description – Clock month

7	6	5	4	3	2	1	0	BIT(S)	
	RSVD		10_MONTH		1_MONTH				
	r/w		r/w	r/w				Read/Write	
0	0	0	Х	Х	Х	Х	Х	Initial	
0	0	0	UC	UC	UC	UC	UC	Cycle	

#### Figure 14. MONTH Register

RSVD Reserved. The RSVD bits should always be written as 0.

10\_MONTH BCD of tens of month. The 10\_MONTH bits are the BCD representation of the tens of month on the clock. Valid values are 0 to 1<sup>(1)</sup>. If invalid data is written to 10\_MONTH, the clock will update with invalid data in 10\_MONTH until the counter rolls over; thereafter, the data in 10\_MONTH is valid.

1\_MONTH BCD of month. The 1\_MONTH bits are the BCD representation of the month on the clock. Valid values are 0 to 9<sup>(1)</sup>. If invalid data is written to 1\_MONTH, the clock will update with invalid data in 1\_MONTH until the counter rolls over; thereafter, the data in 1\_MONTH is valid.

(1) 10\_MONTH and 1\_MONTH must form a valid date, 01 to 12.

#### 7.6.2.7 YEARS Register (address = 0x06) [reset = XXXXXXXb]

Description - Clock year

#### Figure 15. YEARS Register

7	6	5	4	3	2	1	0	BIT(S)
	10_Y	′EAR		1_YEAR				Name
r/w				r/w				Read/Write
X	Х	Х	Х	X X X X				Initial
UC	UC	UC	UC	UC	UC	UC	UC	Cycle

10\_YEAR BCD of tens of years. The 10\_YEAR bits are the BCD representation of the tens of years on the clock. Valid values are 0 to 9. If invalid data is written to 10\_YEAR, the clock will update with invalid data in 10\_YEAR until the counter rolls over; thereafter, the data in 10\_YEAR is valid. Time keeping registers can take up to 1 second to update after the RTC switches from backup power supply to main power supply.

1\_YEAR BCD of year. The 1\_YEAR bits are the BCD representation of the years on the clock. Valid values are 0 to 9. If invalid data is written to 1\_YEAR, the clock will update with invalid data in 1\_YEAR until the counter rolls over; thereafter, the data in 1\_YEAR is valid. Time keeping registers can take up to 1 second to update after the RTC switches from backup power supply to main power supply.

#### 7.6.2.8 CAL\_CFG1 Register (address = 0x07) [reset = 1000000b]

Description - Calibration and control

			0	—	0								
7	6	5	4	3	2	1	0	BIT(S)					
OUT	FT	S			CAL			Name					
r/w	r/w	r/w		r/w R									
1	0	0	0	0 0 0 0 0									
UC	UC	UC	UC	UC	UC	UC	UC	Cycle					
OUT		$\overline{\underline{\lambda}}$ is logic 0 $\overline{\underline{\lambda}}$ is logic 1		ro, the logic out	·								
FT	produced of 0 Dis			le the frequency e SFR register of				quare wave is					
S	slows the R 0 Slo			polarity of the ca in speeds the R		d to the oscillato	or. If S is 0, the	n the calibration					
CAL	Calibration.	The CAL bits a	long with S dete	ermine the calib	ration amount as	s shown in Tabl	e 4.						

Figure 16. CAL\_CFG1 Register

**Table 4. Calibration** 

CAL (DEC)	S = 0	S = 1
0	+0 ppm	–0 ppm
1	+2 ppm	–4 ppm
N	+N / 491520 (per minute)	–N / 245760 (per minute)
30	+61 ppm	–122 ppm
31	+63 ppm	–126 ppm

#### 7.6.2.9 TCH2 Register (address = 0x08) [reset = 10010000b]

Description – Trickle charge TCH2 control

#### Figure 17. TCH2 Register

7	6	5	4	BIT(S)				
RS	VD	TCH2		Name				
r/	w	r/w		Read/Write				
1	0	0	1 0 0 0 0				0	Initial
UC	0	0	1 UC UC UC UC		Cycle			

RSVD TCH2 Reserved. The RSVD bits should always be written as 0.

Trickle charge switch two. The TCH2 bit determines if the internal trickle charge switch is closed or open. All the trickle charge switches must be closed in order for trickle charging to occur. If TCH2 is 0, then the TCH2 switch is open. If TCH2 is 1, then the TCH2 switch is closed.

0 Open

1 Closed



#### 7.6.2.10 CFG2 Register (address = 0x09) [reset = 10101010b]

Description – Configuration 2

7	6	5	4	3	2	1	0	BIT(S)			
RSVD	TCFE	R	SVD		тс	HE		Name			
r/w	r/w	r	/w		r/	w		Read/Write			
1	0	1	<u>    1    0     1    0    1    0    </u>								
1	0	UC	UC	1	0	1	0	Cycle			
RSVD	Reserved. T	he RSVD bits	should always b	e written as 0.							
TCFE		ge FET bypass is 1, the FET	. The TCFE bit i is on.	is used to enable	e the trickle cha	rge FET. When	TCFE is 0, the	FET is off.			
	0 Ope	en									
	1 Clo	sed									
TCHE			TCHE bits dete e charger is inac		de charger is ac	tive. If TCHE is	0x5, then the ti	rickle charger is			

#### Figure 18. CFG2 Register

#### 7.6.3 Special Function Registers

#### 7.6.3.1 SF KEY 1 Register (address = 0x20) [reset = 0000000b]

#### Description – Special function key 1

#### Figure 19. SF KEY 1 Register

7	6	5	4	3	2	1	0	BIT(S)				
	SF KEY B1											
r/w												
0	0 0 0 0 0 0 0 0											
0	0	0	0	0	0	0	0	Cycle				

SF KEY B1 Special function access key byte 1. Reads as 0x00, and key is 0x5E.

The SF KEY 1 and SF KEY 2 registers are used to enable access to the main special function register (SFR). Access to SFR is granted only after the special function keys are written sequentially to SF KEY 1 and SF KEY 2. Each write to the SFR must be preceded by writing the SF keys to the SF key registers, in order, SF KEY 1 then SF KEY 2.

#### 7.6.3.2 SF KEY 2 Register (address = 0x21) [reset = 0000000b]

Description – Special function key 2

#### Figure 20. SF KEY 2 Register

7	6	5	5 4 3 2 1 0									
	SF KEY 2											
	r/w											
0	0 0 0 0 0 0 0 0											
0	0	0	0	0	0	0	0	Cycle				

SF KEY 2

Special function access key byte 2. Reads as 0x00, and key is 0xC7.

The SF KEY 1 and SF KEY 2 registers are used to enable access to the main special function register (SFR). Access to SFR is granted only after the special function keys are written sequentially to SF KEY 1 and SF KEY 2. Each write to the SFR must be preceded by writing the SF keys to the SF key registers, in order, SF KEY 1 then SF KEY 2.

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### 7.6.3.3 SFR Register (address = 0x22) [reset = 0000000b]

Description - Special function register 1

			-		-			
7	6	5	4	3	2	1	0	BIT(S)
		FTF	Name					
		r/w	Read/Write					
0	0	0	0	0	0	0	0	Initial
0	0	0	0	0	0	0	0	Cycle
	December 1		have a la strange b					

#### Figure 21. SFR Register

RSVD FTF Reserved. The RSVD bits should always be written as 0.

Force calibration to 1 Hz. FTF allows the frequency of the calibration output to be changed from 512 Hz to 1 Hz. By default, FTF is cleared, and the RTC outputs a 512-Hz calibration signal. Setting FTF forces the calibration signal to 1 Hz, and the calibration tracks the internal ppm adjustment. Note: The default 512-Hz calibration signal does not include the effect of the ppm adjustment.

0 Normal 512-Hz calibration

1 1-Hz calibration



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## 8 Application and Implementation

#### NOTE

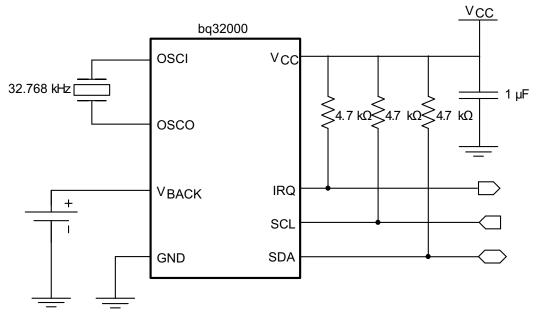
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

#### 8.1 Application Information

The typical application for the bq32000 is to provide precise time and date to a system. The backup power supply provides additional reliability by automatically switching over from the main supply when it drops under the voltage threshold.

### 8.2 Typical Application

The following design is a common application of the bq32000.





#### 8.2.1 Design Requirements

The design requirement parameters are listed in the following table.

#### **Table 5. Design Parameters**

DESIGN PARAMETER	REFERENCE	EXAMPLE VALUE
Supply Voltage	V <sub>CC</sub>	3.3 V
Backup Supply	V <sub>BACK</sub>	BR1225
Crystal Oscillator	ХТ	32.768 kHz



#### 8.2.2 Detailed Design Procedure

#### 8.2.2.1 Reading From a Register

The report details the read-back of the SECONDS register. Figure 23 depicts the first condition that will be used as a benchmark to compare the values taken from the SECONDS register in the bq32000, to the oscilloscope's internal PC time. In this example two modes of operation are demonstrated.

Condition 1. The main power supply,  $V_{CC}$ , is greater than the backup power supply,  $V_{BACK}$ , and the internal reference voltage,  $V_{REF}$ . In this mode, the device's internal registers are fully operational with READ and WRITE access. Analyzing Figure 23, the known register values are compared to the system clock; in this case, the PC clock which is shown at the bottom of the screen capture.

The bq32000 during this condition is reading back [101][0010]= [5][2], which corresponds to 52 seconds at PC time of 2:22:43 PM.

Condition 2.  $V_{CC}$  is now lowered to 2 V ( $V_{BACK} > V_{CC}$ ). In this mode, the I2C communications are halted. However, the internal time keeping registers maintain full functional operation and accuracy which will be available to be reliably read by the controller 1 second after the RTC switches from  $V_{BACK}$  to  $V_{CC}$  supply.

Condition 3. During this final test condition, the RTC is restored to operate from the main power supply and I2C communications are now fully functional.

Figure 24 demonstrates a read-back value from the SECONDS register of [100][0101] = [4][5], or 45 seconds at PC time of 2:23:36 PM. This proves that the bq32000 managed to accurately maintain the time keeping registers functional while the V<sub>CC</sub> dropped below V<sub>BACK</sub>.

#### 8.2.2.2 Leap Year Compensation

The BQ32000 classifies a leap year as any year that is evenly divisible by 4. Using this rule allows for reliable leap year compensation until 2100. Years that fall outside this rule will need to be compensated for by the external controller.

#### 8.2.2.3 Utilizing the Backup Supply

In order for the bq32000 to achieve a low backup supply current as specified in the *Electrical Characteristics*, the  $V_{CC}$  pin must be initialized after every total power loss situation. Initialization Is achieved by powering on  $V_{CC}$  with a voltage between 3 to 3.6 V for at least 1 ms immediately after the backup supply is connected. If the  $V_{CC}$  is not powered on while connecting the backup supply, then the expected leakage current from  $V_{BACK}$  will be much greater than specified.



#### 8.2.3 Application Curves

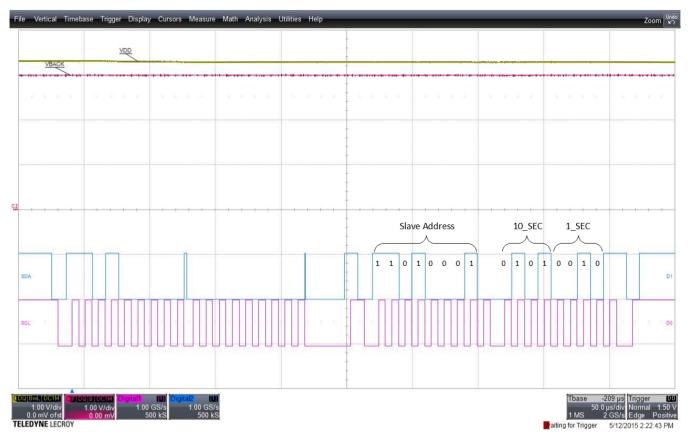


Figure 23. Master and Slave I<sup>2</sup>C Communication for the SECONDS Register

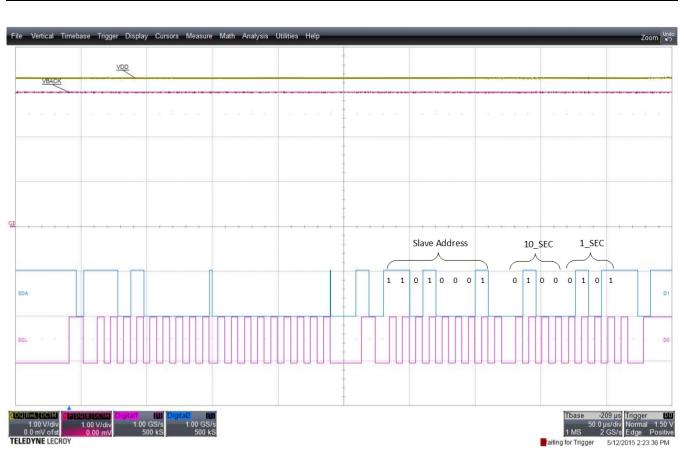


Figure 24. Master and Slave I<sup>2</sup>C Communication for the SECONDS Register After Recovering From the Backup Supply



bq32000

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### 9 Power Supply Recommendations

The bq32000 is designed to operate from an input voltage supply, V<sub>CC</sub>, range between 3.0 and 3.6 V. The user must place a minimum of 1- $\mu$ F ceramic bypass capacitor rated for at least the maximum voltage as close as possible to V<sub>CC</sub> and GND pin.

## 10 Layout

#### 10.1 Layout Guidelines

The V<sub>CC</sub> pin should be bypassed to GND using a low-ESR ceramic bypass capacitor with a minimum recommended value of 1- $\mu$ F. This capacitor should be placed as close to the V<sub>CC</sub> and GND pins as possible with thick trace or ground plane connection to the device GND pin.

Locate the 32.768-kHz crystal oscillator as close as possible to the OSCI and OSCO pins. This will minimize stray capacitance.

#### **10.2 Layout Example**

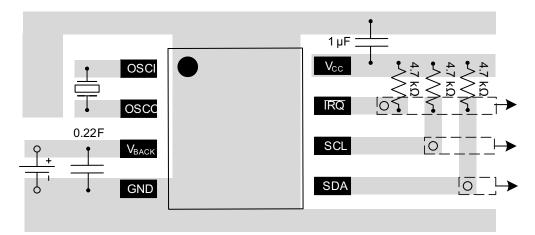


Figure 25. Recommended PCB Layout



## **11** Device and Documentation Support

#### 11.1 Device Support

#### 11.1.1 Third-Party Products Disclaimer

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#### **11.2 Community Resources**

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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**Design Support TI's Design Support** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 11.3 Trademarks

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

#### **11.4 Electrostatic Discharge Caution**



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## 11.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

#### 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



10-Dec-2020

## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
BQ32000D	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	32000	Samples
BQ32000DR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	32000	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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## PACKAGE OPTION ADDENDUM

10-Dec-2020

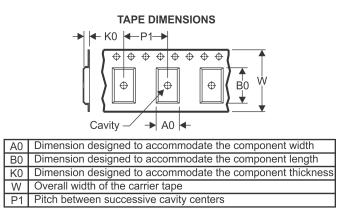
# PACKAGE MATERIALS INFORMATION

Texas Instruments

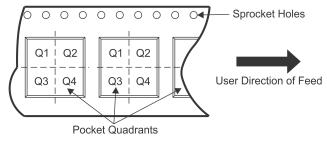
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## TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions a	are nominal
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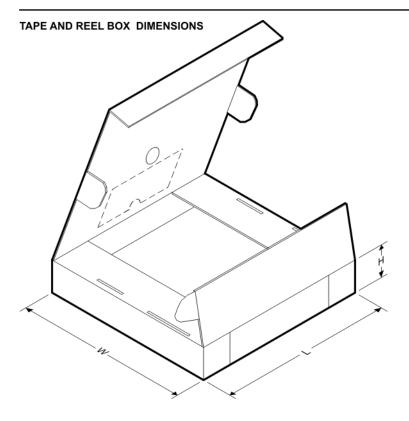
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
BQ32000DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

Pack Materials-Page 1



## PACKAGE MATERIALS INFORMATION

5-Jan-2022



\*All dimensions are nominal

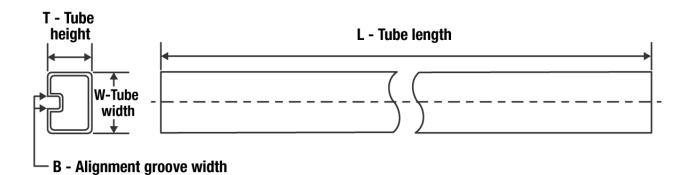
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
BQ32000DR	SOIC	D	8	2500	367.0	367.0	35.0

Pack Materials-Page 2



5-Jan-2022

## TUBE



#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
BQ32000D	D	SOIC	8	75	506.6	8	3940	4.32

Pack Materials-Page 3

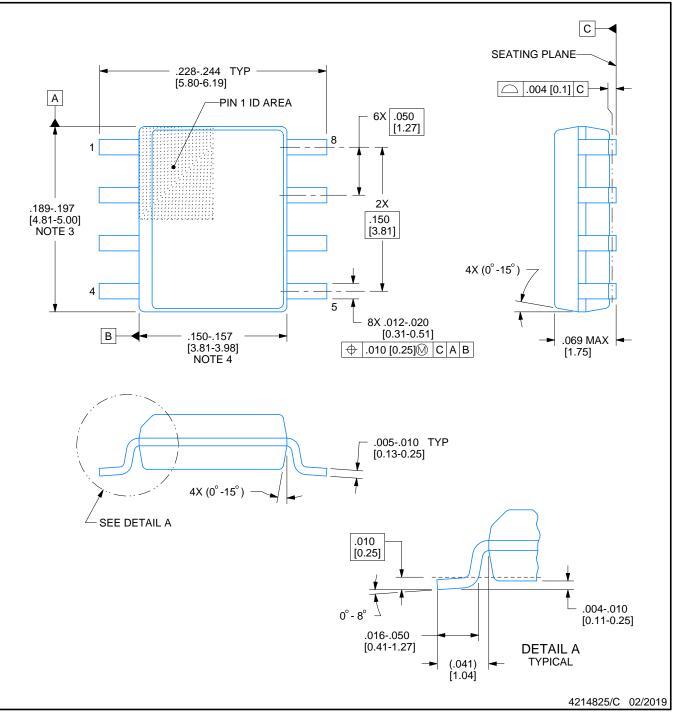
# D0008A



# **PACKAGE OUTLINE**

## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



# D0008A

# **EXAMPLE BOARD LAYOUT**

## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

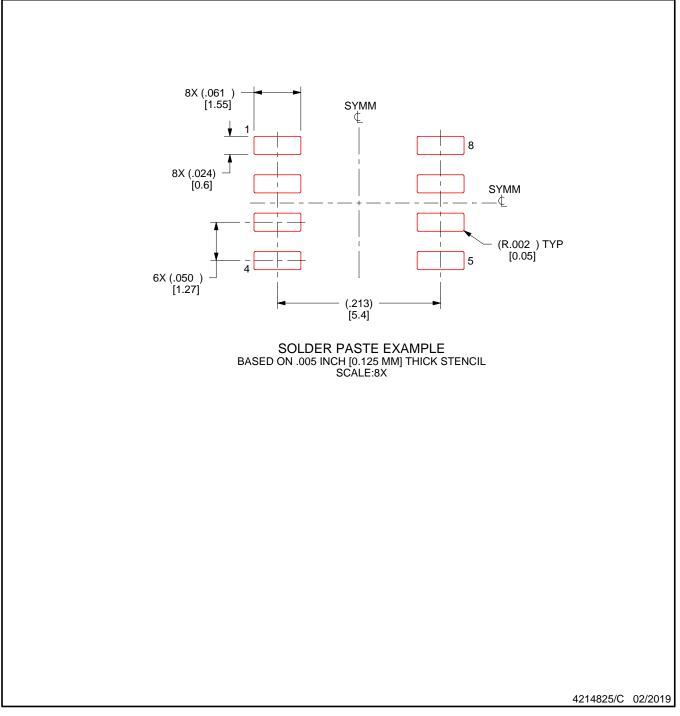


# D0008A

# **EXAMPLE STENCIL DESIGN**

## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



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